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INFORMATION DISCLOSURE		APPLICANTS		
CITATION		Burton et al		
(Use several sheets if necessary)		FILING DATE	GROUP ART UNIT	
			2523	
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)				
Lee	Murakami, M. et al, <i>Thermally stable, low-resistance NiInW ohmic contacts to</i> 'n-type GaAs, Appl. Phys. Lett. 51 (9), 31 Aug. 1987, pp. 664-666.			
, i	Piotrowska, A. et al, Ohmic Contacts to III-V Compound Semiconductors: A			
[	Review of Fabrication Techniques, pp. 179-197. Solid State Electronics, 12			
	Jan. 1982.			
	'Yoder, M., Ohmic Contacts in GaAs, Solid State Electronics, Vol. 23, 30 May			
	1979, pp.117-119.			
	Tanahashi, K. et al, Thermally stable non-gold Ohmic contacts to n-type GaAs.			
	I. NiGe contact metal, Appl. Phys. Lett. 72 (9), 1 Nov. 1992, pp. 4183-4190.			
	Murakami, M. et al, Thermally stable, low resistance Ohmic contacts to n-type			
GaAs, Proc. of Gallium Arsenide and related components, 1987.				
	Murakami, M. et al, Thermally stable ohmic contacts to n-type GaAs: II.  MoGeinW contact metal, J. Appl. Phys., Oct 1987.			
	Murakami, M. et al, Thermally stable ohmic contacts to n-type GaAs. v. Metal-			
	semiconductor field-effect transistors with NiInW ohmic contacts, J. Appl.			
	Phys. 65 (9), 1 May 1989, pp. 3546-3551.			
	Hugon, M. et al, Highly stable sputtered NiInW refractory ohmic contact to n-			
	type GaAs, J. Appl. Phys. 72 (8) 15 Oct. 1992, pp. 3570-3577.			
	Oku, T. et al, NiGe-based ohmic contacts to ntype GaAs. I. Effects of In			
	addition, J. Appl. Phys. 75 (5), 1 Mar. 1994, pp. 2522-2529.			
	Shih, Y. et al, Thermally stable ohmic contacts to n-type GaAs. IV. Role of Ni on NiInW contacts, J. Appl. Phys. 65 (9), 1 May 1989, pp. 3539-3545.			
P	Jan, C., et al, Alloying of Ni/In/n-GaAs ohmic contacts induced by Ga-Ni-As			
ternary eutectic reactions, J. Appl. Phys. 68 (12), 15 Dec. 1990, pp. 6458-6462				
EXAMINER DATE CONSIDERED 9/2/51				
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